

# 1A, 50V - 1000V Surface Mount Rectifiers

## FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition





DO-214AC (SMA)

MECHANICAL DATA Case: DO-214AC (SMA) Molding compound, UL flammability classification rating 94V-0 Moisture sensitivity level: level 1, per J-STD-020 Part no. with suffix "H" means AEC-Q101 qualified Packing code with suffix "G" means green compound (halogen-free) Terminal: Matte tin plated leads, solderable per JESD22-B102 Meet JESD 201 class 2 whisker test Polarity: Indicated by cathode band Weight: 0.06 g (approximately)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> =25°C unless otherwise noted)									
PARAMETER	SYMBOL	S1A	S1B	S1D	S1G	S1J	S1K	S1M	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	I <sub>F(AV)</sub>	1			А				
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	40 30			A				
Maximum instantaneous forward voltage (Note 1) @ 1 A	V <sub>F</sub>	1.1 V			V				
Maximum reverse current @ rated $V_R$ T <sub>J</sub> =25°C T <sub>J</sub> =125°C	١ <sub>R</sub>	1 50			μA				
Typical reverse recovery time (Note 2)	t <sub>rr</sub>	1.5 µ			μs				
Typical junction capacitance (Note 3)	CJ	12			pF				
Non-repetitive peak reverse avalanche energy at 25°C, I <sub>AS</sub> =1A, L=10mH	E <sub>RSM</sub>	5 r			mJ				
Typical thermal resistance	R <sub>θJL</sub> R <sub>θJA</sub>			30 35	°C/W				
Operating junction temperature range	TJ	- 55 to +175 °C			°C				
Storage temperature range	T <sub>STG</sub>	- 55 to +175			°C				

Note 1: Pulse test with PW=300µs, 1% duty cycle

Note 2: Reverse Recovery Test Conditions:  $I_F$ =0.5A,  $I_R$ =1.0A,  $I_{RR}$ =0.25A

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

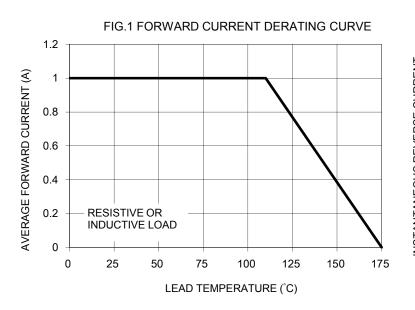


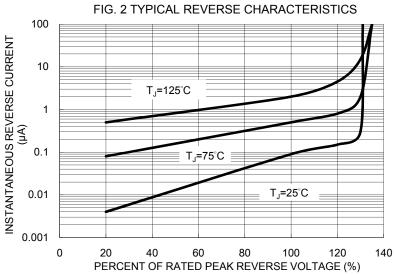
ORDERING INFORMATION						
PART NO.	PART NO.	PACKING CODE	PACKING CODE	PACKAGE	PACKING	
	SUFFIX		SUFFIX			
S1x H (Note 1)		R3		SMA	1,800 / 7" Plastic reel	
	R2		SMA	7,500 / 13" Paper reel		
		M2	G	SMA	7,500 / 13" Plastic reel	
	ц	F3		Folded SMA	1,800 / 7" Plastic reel	
	п	F2		Folded SMA	7,500 / 13" Paper reel	
		F4		Folded SMA	7,500 / 13" Plastic reel	
		E3		Clip SMA	1,800 / 7" Plastic reel	
		E2		Clip SMA	7,500 / 13" Plastic reel	

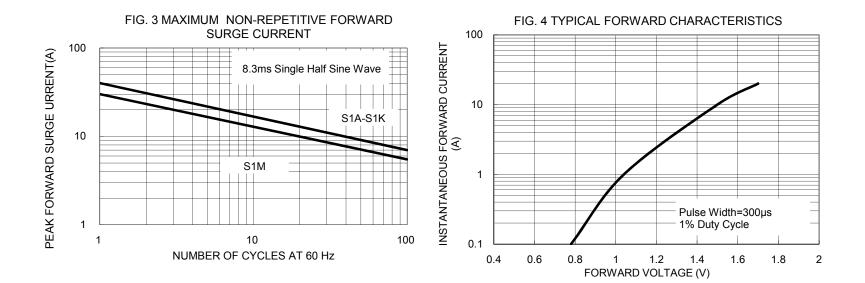
Note 1: "x" defines voltage from 50V (S1A) to 1000V (S1M)

EXAMPLE						
PREFERRED PART NO.	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION	
S1MHR3G	S1M	Н	R3	G	AEC-Q101 qualified Green compound	

### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub>=25°C unless otherwise noted)







Document Number: DS\_D1411068



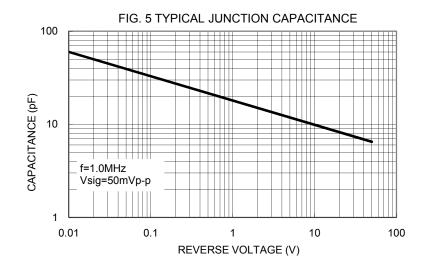
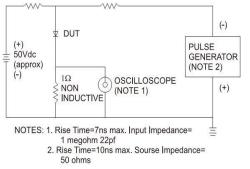
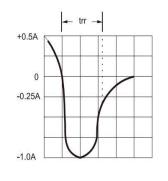


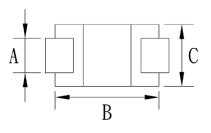
FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

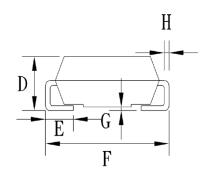
#### 50Ω NONINDUCTIVE 10Ω NONINDUCTIVE





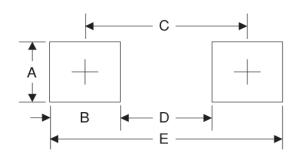
PACKAGE OUTLINE DIMENSIONS DO-214AC (SMA)





DIM.	Unit	(mm)	Unit (inch)			
	Min	Max	Min	Мах		
А	1.27	1.58	0.050	0.062		
В	4.06	4.60	0.160	0.181		
С	2.29	2.83	0.090	0.111		
D	1.99	2.50	0.078	0.098		
E	0.90	1.41	0.035	0.056		
F	4.95	5.33	0.195	0.210		
G	0.10	0.20	0.004	0.008		
Н	0.15	0.31	0.006	0.012		

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	1.68	0.066
В	1.52	0.060
С	3.93	0.155
D	2.41	0.095
E	5.45	0.215

## **MARKING DIAGRAM**



- P/N =Specific Device Code G = Green Compound
- YW = Date Code
- F = Factory Code



### Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below :

MCL4151-TR3 MMBD3004S-13-F RD0306T-H RD0506LS-SB-1H RGP30G-E373 DSE010-TR-E BAQ333-TR BAQ335-TR BAQ33-GS18 BAS1602VH6327XT BAV17-TR BAV19-TR BAV301-TR BAW27-TAP HSC285TRF-E NSVBAV23CLT1G NTE525 1SS181-TP 1SS184-TP 1SS193,LF 1SS193-TP 1SS400CST2RA SBAV99LT3G SDAA13 LL4448-GS18 SHN2D02FUTW1T1G LS4150GS18 LS4151GS08 SMMBD7000LT3G FC903-TR-E 1N4449 1N4934-E3/73 1SS226-TP APT100DL60HJ RFUH20TB3S RGP30G-E354 RGP30M-E3/73 D291S45T MCL4151-TR BAS 16-02V H6327 BAS 21U E6327 BAS 28 E6327 BAS33-TAP BAS 70-02V H6327 BAV300-TR BAV303-TR3 BAW27-TR BAW56DWQ-7-F BAW56M3T5G BAW75-TAP